



**THE DATASHEET OF
RT5735AWSC**



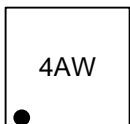
5A Step-Down Converter with I²C Interface

General Description

The RT5735A device is a full featured 5.5V, 5A, synchronous step down constant-on-time (COT) current mode converter with two integrated MOSFETs. The RT5735A enables small designs by integrating the MOSFETs, implementing current mode control to reduce external component count, reducing inductor size by enabling up to 2.4MHz switching frequency, and minimizing the IC footprint with a small WL-CSP-20B 1.6x2 (BSC) package. The RT5735A provides accurate regulation for a variety of loads with an accurate ±1% Voltage Reference (VREF) over temperature. Efficiency is maximized through the integrated 34mΩ/18mΩ MOSFETs and 70μA typical quiescent current. Using the enable pin, shutdown supply current is less than 2μA by entering a shutdown mode.

The output voltage startup ramp is controlled by the slow start pin. An open-drain power good signal indicates the output is within 90% to 95% of its nominal voltage.

Marking Information



4A : Product Code
W : Date Code

Features

- 2.5V to 5.5V Input Supply Voltage
- Current Mode COT Control Loop Design
- Fast Transient Response
- Internal 34mΩ and 18mΩ Synchronous Rectifier
- Highly Accurate V_{OUT} Regulation Over Load/Line Range
- Robust Loop Stability with Low-ESR C_{OUT}
- Over-Temperature Protection

Applications

- Distributed Power Systems
- Enterprise Servers, Ethernet Switches & Routers, and Global Storage Equipment
- Telecom & Industrial Equipment

Ordering Information

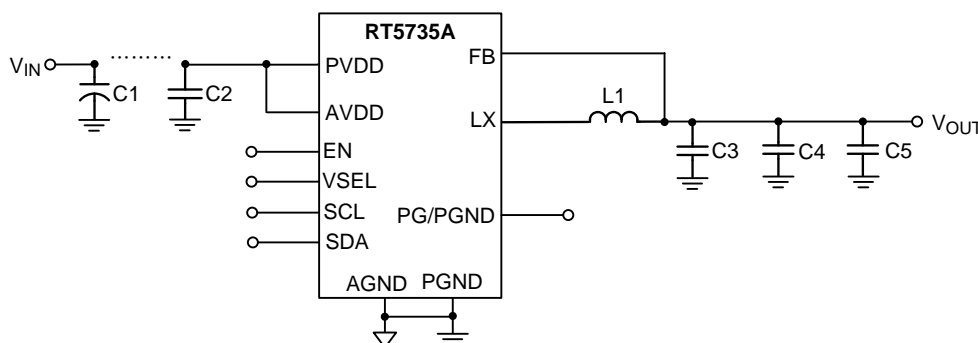
RT5735A □
 Package Type
 WSC : WL-CSP-20B 1.6x2 (BSC)

Note :

Richtek products are :

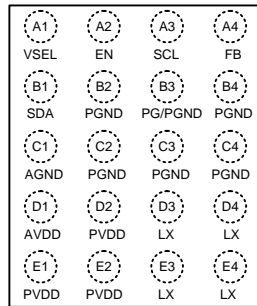
- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

Simplified Application Circuit



Pin Configurations

(TOP VIEW)

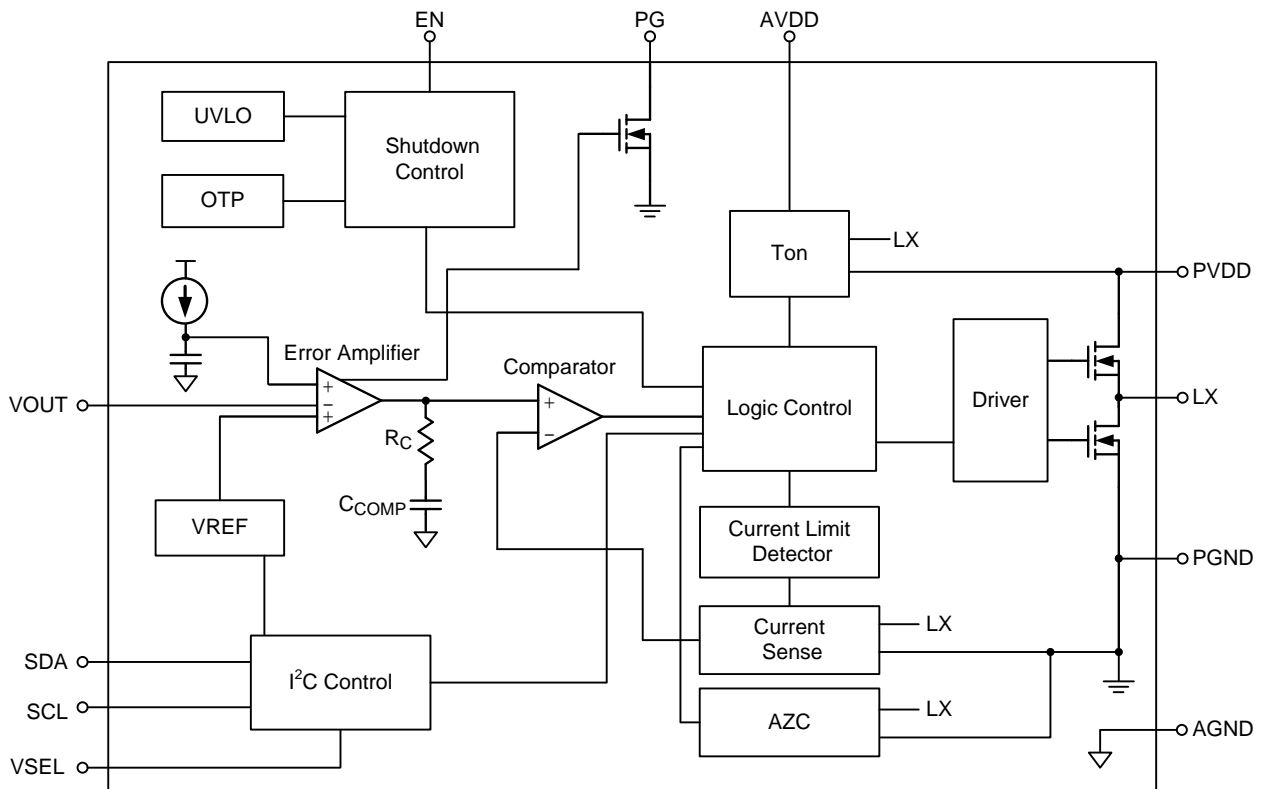


WL-CSP-20B 1.6x2 (BSC)

Functional Pin Description

| Pin No. | Pin Name | Pin Function |
|--------------------|----------|---|
| A1 | VSEL | Output Voltage/ Mode Selection. The level determines which of two programmable, configurations to utilize (operating mode / output voltage). There is an internal pull down resistor on this pin; could be left open if not used. |
| A2 | EN | Enable Control Input. Active high will enable the part. There is an internal pull-down resistor on this pin. |
| A3 | SCL | I ² C Clock Input. |
| A4 | FB | Output Voltage Pin. |
| B1 | SDA | I ² C Data Input. |
| B3 | PG/PGND | Power Good Open-Drain Output. If not used, it has to be connected to ground plane. |
| B2, B4, C2, C3, C4 | PGND | Power Ground. |
| C1 | AGND | Analog Ground should be electrically connected to GND close to the device. |
| D1 | AVDD | Analog Circuit Input Supply Voltage. |
| D2, E1, E2 | PVDD | Input Supply Voltage, 2.5V to 5.5V. |
| D3, D4, E3, E4 | LX | Switch Node. The source of the internal high-side power MOSFET, and drain of the internal low-side (synchronous) rectifier MOSFET. |

Function Block Diagram



Operation

The RT5735A is a synchronous low voltage step-down converter that can support the input voltage range from 2.5V to 5.5V and the output current can be up to 5A. The RT5735A uses a constant on-time, current mode architecture. In steady-state operation, the high-side N-MOSFET is turned on when the current feedback reaches COMP level which is the amplified difference between the reference voltage and the feedback voltage. The on time of high-side N-MOSFET is determined by on-time generator which is a function of input and output voltage. After on-time expires, high-side MOSFET is turned off and low-side MOSFET is turned on. Until the low-side current sensing signal reaches the COMP, the high-side MOSFET is turned on again. In this manner, the converter regulates the output voltage and keeps the frequency constant.

The switching frequency is 2.4MHz allows for efficiency and size optimization when selecting the output filter components.

The RT5735A reduces the external component count by integrating the boot recharge MOSFET.

The error amplifier EA adjusts COMP voltage by comparing the output voltage with the internal I²C set reference voltage. When the load increases, it causes a drop in the output voltage relative to the reference, then the COMP voltage rises to allow higher inductor current to match the load current.

PWM Frequency and Adaptive On Time Control

The on-time can be roughly estimated by the equation :

$$T_{on} = \frac{V_{OUT}}{V_{IN}} \times \frac{1}{F_{SW}} \text{ where } F_{SW} \text{ is nominal } 2.4\text{MHz}$$

Auto-Zero Current Detector

The auto-zero current detector circuit senses the LX waveform to adjust the zero current threshold voltage. When the current of low-side MOSFET decreases to the zero current threshold, the low-side MOSFET turns off to prevent negative inductor current. In this way, the zero current threshold can adjust for different condition to get better efficiency.

Protection Features

The RT5735A has many features to protect the device.

Under-Voltage Protection (UVLO)

The UVLO continuously monitors the voltage of AVDD to make sure the device works properly. When the AVDD is high enough to reach the high threshold voltage of UVLO, the step-down converter softly starts or pre-bias to its regulated output voltage. When the AVDD decreases to its low threshold (180mV hysteresis), the device will shut down.

Power Good

When the output voltage is higher than PG rising threshold, the PG flag is High.

Output Under-Voltage Protection (UVP)

When the output voltage is lower than 400mV after soft-start end is ok, the UVP is triggered. When UVP occurs, the device enters hiccup mode.

Over-Current Protection (OCP)

The RT5735A senses the current signal when low-side MOSFET turns on and uses a valley current limiting circuit. As a result, the OCP set point is the OCP DC limit minus half of the ripple current. The OCP is cycle-by-cycle limit. If the OCP occurs, the converter holds off the next on pulse until inductor current drops below the OCP limit. If the OCP keeps and the load current is larger than the current provided by the converter, the output voltage drops. When the output voltage triggers UVP, the converter enters hiccup mode.

Soft-Start

An internal current source charges an internal capacitor to build the soft-start ramp voltage. The typical soft-start time is 130 μ s.

Over-Temperature Protection (OTP)

The RT5735A has over-temperature protection. When the device triggers the OTP, the device shuts down.

Absolute Maximum Ratings (Note 1)

- Supply Input Voltage, V_{IN} ----- -0.3V to 6V
- Other Pins ----- -0.3V to $V_{IN} + 0.3V$
- Power Dissipation, P_D @ $T_A = 25^\circ C$
 WL-CSP-20B 1.6x2 (BSC) ----- 1.818W
- Package Thermal Resistance (Note 2)
 WL-CSP-20B 1.6x2 (BSC), θ_{JA} ----- $55^\circ C/W$
 WL-CSP-20B 1.6x2 (BSC), θ_{JC} ----- $7^\circ C/W$
- Lead Temperature (Soldering, 10 sec.) ----- $260^\circ C$
- Junction Temperature ----- $150^\circ C$
- Storage Temperature Range ----- $-65^\circ C$ to $150^\circ C$
- ESD Susceptibility (Note 3)
 HBM (Human Body Model) ----- 2kV

Recommended Operating Conditions (Note 4)

- Supply Input Voltage ----- 2.5V to 5.5V
- Ambient Temperature Range ----- $-40^\circ C$ to $85^\circ C$
- Junction Temperature Range ----- $-40^\circ C$ to $125^\circ C$

Electrical Characteristics

($V_{IN} = 3.6V$, $T_A = 25^\circ C$, unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit | |
|---------------------------------|------------------|---|---------------|-----|------|---------|------------|
| Supply Current | | | | | | | |
| Operating Quiescent Current PWM | I_{Q_PWM} | PWM Mode IQ at $I_{OUT} = 0A$ (Note 5) | -- | 10 | 20 | mA | |
| Operating Quiescent Current PFM | I_{Q_PFM} | PSM Mode IQ at $I_{OUT} = 0A$ | -- | 70 | -- | μA | |
| Product in Off Mode | I_{OFF} | EN, VSEL Low, $V_{IN} = 2.5V$ to $5.5V$ | -- | 1 | 5 | μA | |
| DC/DC Converter | | | | | | | |
| Operation Input Voltage | V_{IN} | | 2.5 | -- | 5.5 | V | |
| Output Voltage DC Error | ΔV_{OUT} | PWM Mode | -1 | -- | 1 | % | |
| | | PSM Mode | -1 | -- | 2 | | |
| Switching Frequency | F_{SW} | | 2.16 | 2.4 | 2.64 | MHz | |
| R_{ON} | High-Side | R_{ON_H} | $V_{IN} = 5V$ | -- | 34 | -- | m Ω |
| | Low-Side | R_{ON_L} | $V_{IN} = 5V$ | -- | 18 | -- | |
| Valley Current Limit Level | $I_{LIM,Valley}$ | $I_{OC} = 00$ Valley Current (Note 5) | -- | 4 | -- | A | |
| | | $I_{OC} = 01$ Valley Current (Note 5) | -- | 4.7 | -- | | |
| | | $I_{OC} = 10$ Valley Current (Note 5) | -- | 5.4 | -- | | |
| | | $I_{OC} = 11$ Valley Current | 5.4 | 6.4 | 7.4 | | |

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|------------------------------------|--------------------------|---|------|------|------|------|
| Load Regulation | ΔV_{LOAD} | I _{OUT} from 300mA to I _{OUTMAX} (Note 5) | -- | 0.2 | -- | %/A |
| Line Regulation | ΔV_{LINE} | 2.5V ≤ V _{IN} ≤ 5.5V | -- | 0.3 | -- | % |
| Transient Load Response | AC _{LOAD} | tr = ts = 0.1μs Load Step 0 to 1.2A (Note 5) | -- | ±40 | -- | mV |
| Turn On Time | T _{start} | Time from EN Transition from Low to High to 90% of Output Voltage | -- | 70 | -- | μs |
| | | Time from EN Transition from Low to High to V _{OUT} | -- | 130 | -- | |
| DC/DC Active Output Discharge | R _{DISCHG} | Force V _{OUT} = 1.15V, EN = Low | -- | 16 | -- | Ω |
| EN, VSEL | | | | | | |
| Input Voltage | Logic-High | V _{IH} | 1.05 | -- | -- | V |
| | Logic-Low | V _{IL} | -- | -- | 0.4 | |
| PG | | | | | | |
| Power Good High Hysteresis | V _{PGH} | Rising Edge as a Percentage of Nominal Output Voltage | 90 | 94 | 98 | % |
| Power Good Low Threshold | V _{PGL} | Falling Edge as a Percentage of Nominal Output Voltage | 86 | 90 | 94 | % |
| Power Good Reaction Time for DC/DC | T _{RT} | Falling | -- | 3.5 | -- | μs |
| | | Rising | 3.5 | -- | 14 | |
| Power Good Low Output Voltage | V _{PGL} | I _{PG} = 5mA | -- | -- | 0.2 | V |
| Power Good Leakage Current | PG _{LK} | 3.6V at PG Pin when Power Good Valid | -- | -- | 100 | nA |
| Power Good High Output Voltage | V _{PGH} | Open-Drain | -- | -- | 5.5 | V |
| I²C | | | | | | |
| High Level at SCL/SDA Line | V _{I2CINT} | | 1.7 | -- | 5 | V |
| SCL, SDA Input Voltage | Logic-High | V _{I2CIH} | 1.7 | -- | -- | V |
| | Logic-Low | V _{I2CIL} | -- | -- | 0.5 | |
| SDA Low Output Voltage | V _{I2COL} | I _{SINK} = 3mA | -- | -- | 0.4 | V |
| I ² C Clock Frequency | F _{SCL} | (Note 5) | -- | -- | 3.4 | MHz |
| Total Device | | | | | | |
| Under-Voltage Lockout Threshold | V _{UVLO} | V _{IN} Falling | -- | 2.15 | 2.34 | V |
| V _{IN} POR | V _{POR} | V _{IN} Rising | -- | 2.3 | 2.45 | V |
| Thermal Shutdown Protection | T _{SD} | (Note 5) | -- | 150 | -- | °C |
| Warning Rising Edge | T _{WARNING} | (Note 5) | -- | 135 | -- | °C |
| Pre-Warning Threshold | T _{PWTH} | For Default Setting (Note 5) | -- | 105 | -- | °C |
| Thermal Shutdown Hysteresis | T _{SDH} | (Note 5) | -- | 30 | -- | °C |
| Thermal Warning Hysteresis | T _{WARNING_HYS} | (Note 5) | -- | 15 | -- | °C |

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------|-----------------|-----|-----|-----|------|
| Thermal Pre-Warning Hysteresis | TPWTH_HYS | (Note 5) | -- | 6 | -- | °C |

Note 1. Stresses beyond those listed “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

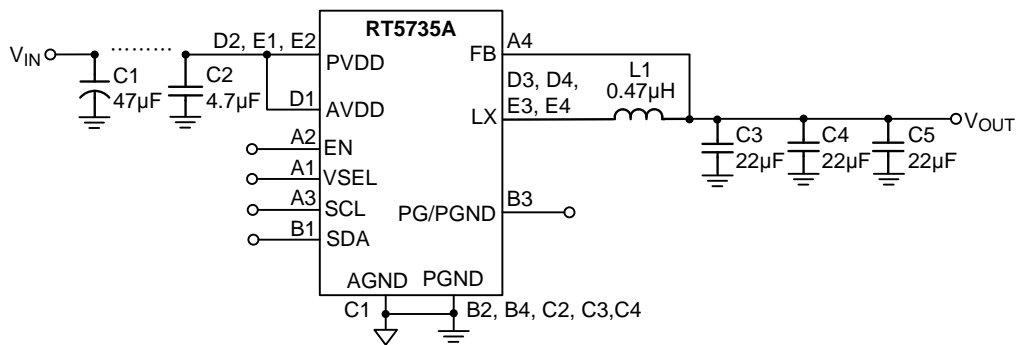
Note 2. θ_{JA} is measured at $T_A = 25^\circ\text{C}$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JC} is measured at the exposed pad of the package.

Note 3. Devices are ESD sensitive. Handling precaution recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.

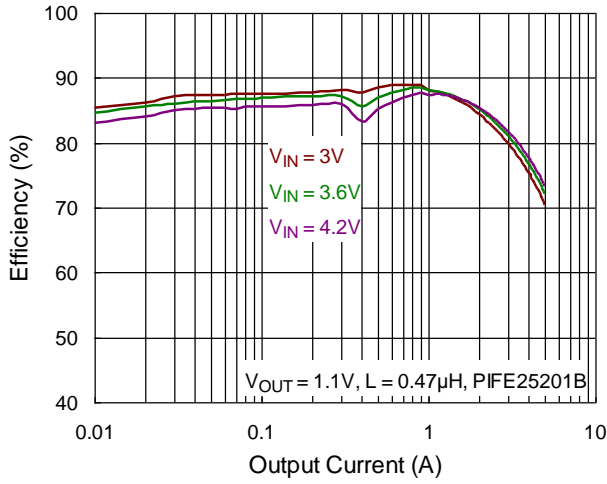
Note 5. Guaranteed by design and characterized.

Typical Application Circuit

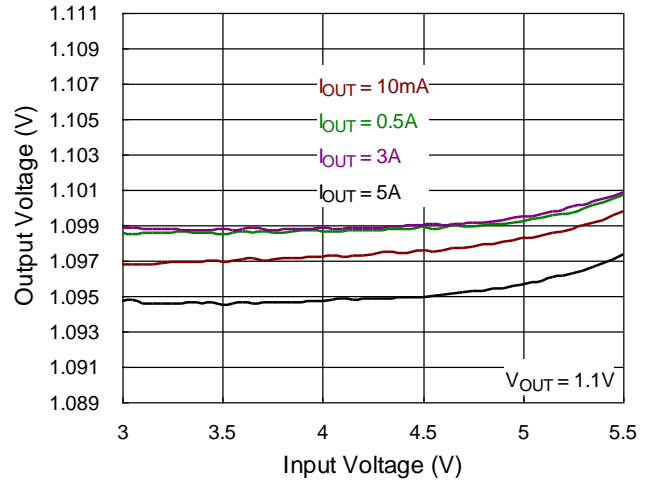


Typical Operating Characteristics

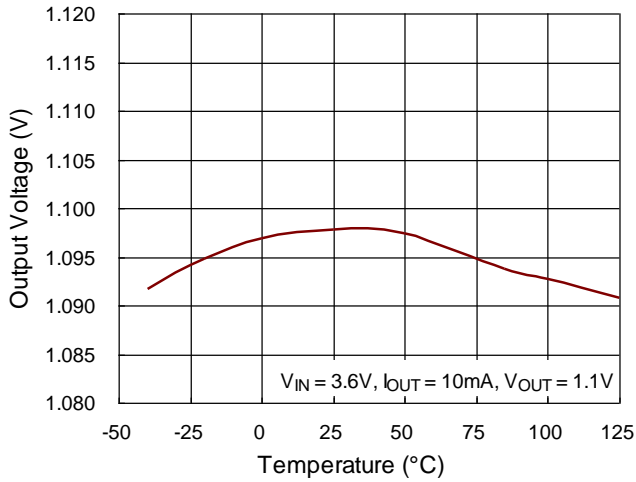
Efficiency vs. Output Current



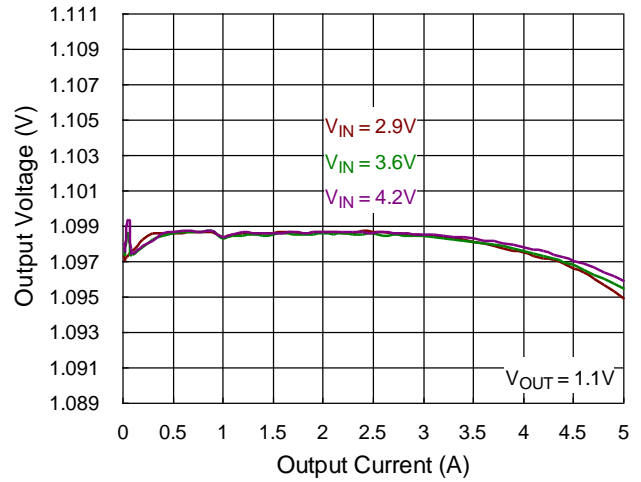
Output Voltage vs. Input Voltage



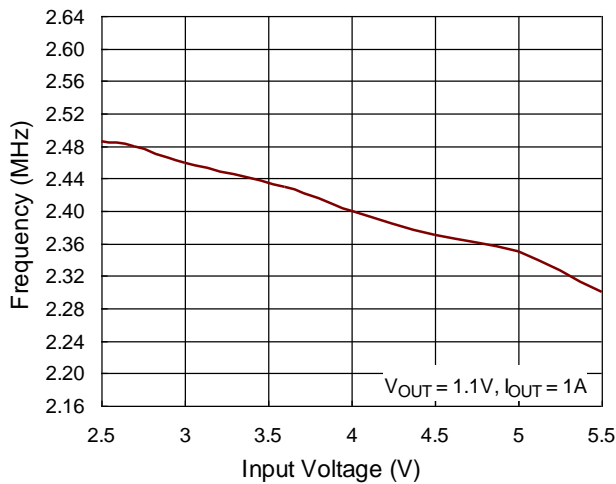
Output Voltage vs. Temperature



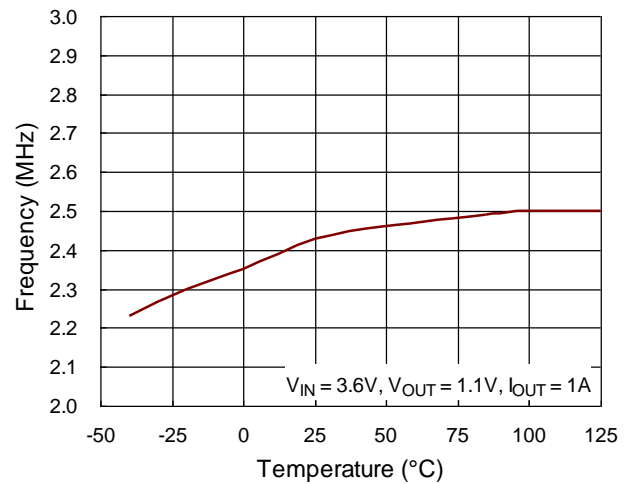
Output Voltage vs. Output Current



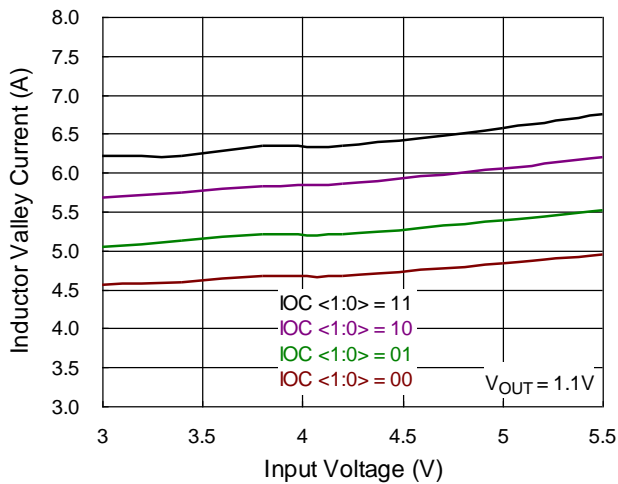
Frequency vs. Input Voltage



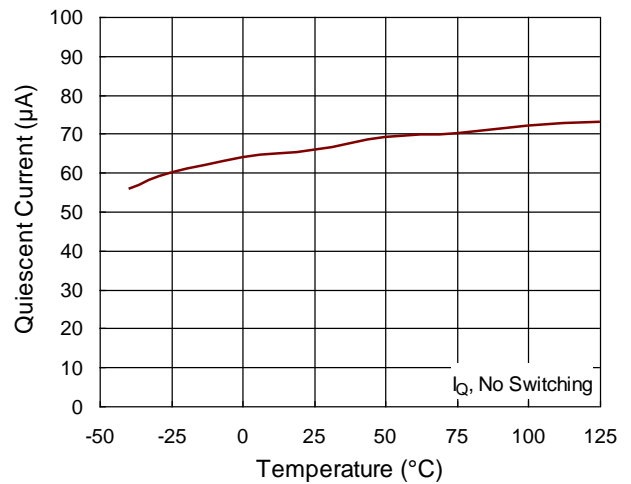
Frequency vs. Temperature



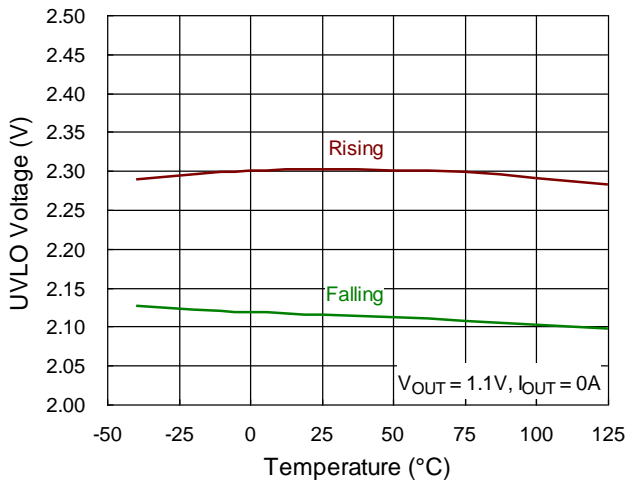
Current Limit vs. Input Voltage



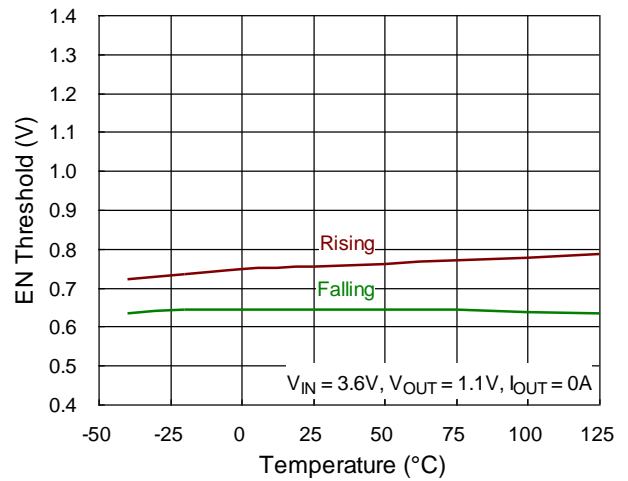
Quiescent Current vs. Temperature



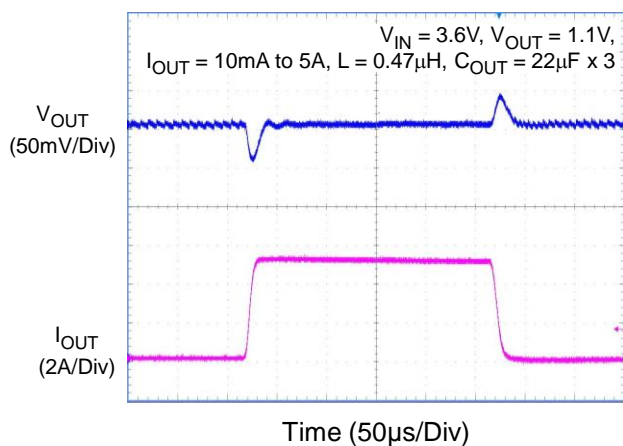
UVLO Voltage vs. Temperature



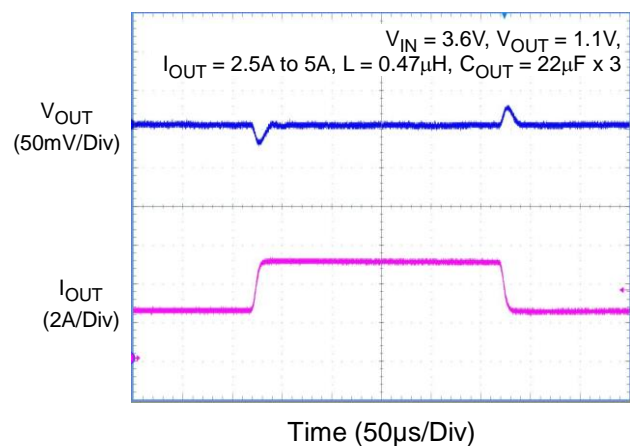
EN Threshold vs. Temperature



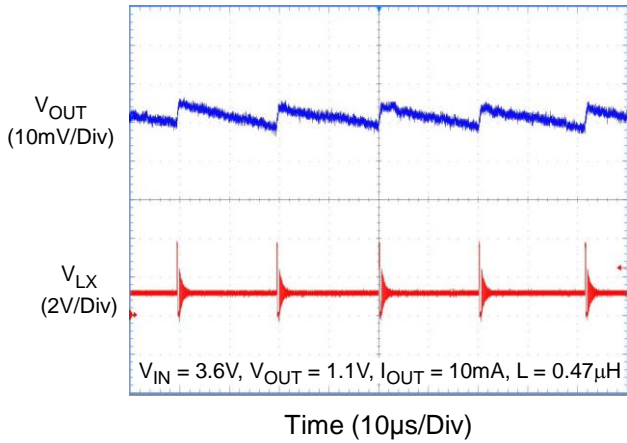
Load Transient Response



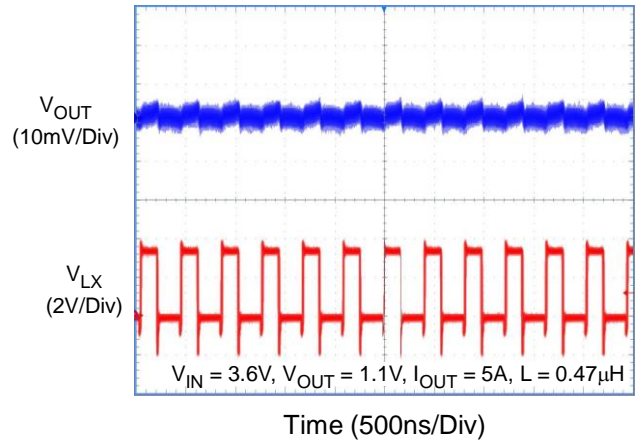
Load Transient Response



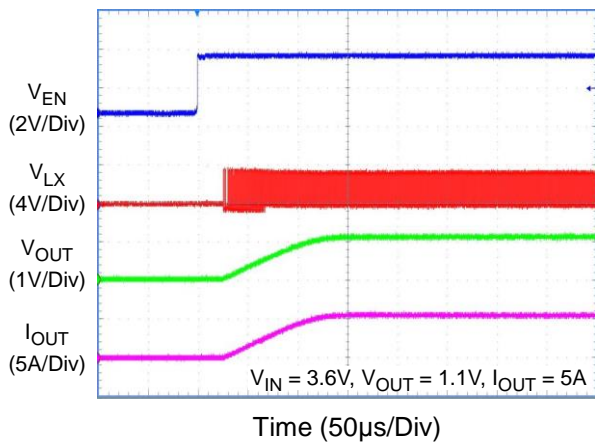
Output Ripple Voltage



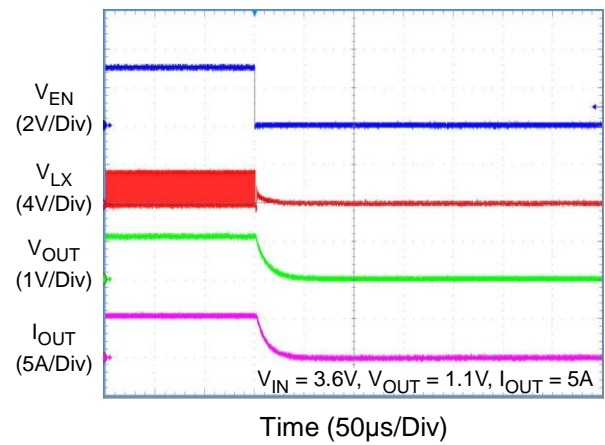
Output Ripple Voltage



Power On from EN



Power Off from EN



Application Information

The basic RT5735A application circuit is shown in Typical Application Circuit. External component selection is determined by the maximum load current and begins with the selection of the inductor value and operating frequency followed by C_{IN} and C_{OUT} .

Inductor Selection

The inductor value and operating frequency determine the ripple current according to a specific input and output voltage. The ripple current, ΔI_L , increases with higher V_{IN} and decreases with higher inductance, as shown in equation below :

$$\Delta I_L = \left[\frac{V_{OUT}}{f \times L} \right] \times \left[1 - \frac{V_{OUT}}{V_{IN}} \right]$$

where f is the operating frequency and L is the inductance. Having a lower ripple current reduces not only the ESR losses in the output capacitors, but also the output voltage ripple. Higher operating frequency combined with smaller ripple current is necessary to achieve high efficiency. Thus, a large inductor is required to attain this goal. The largest ripple current occurs at the highest V_{IN} . A reasonable starting point for selecting the ripple current is $\Delta I_L = 0.3 \times I_{MAX}$ to $0.4 \times I_{MAX}$. To guarantee that the ripple current stays below a specified maximum, the inductor value should be chosen according to the following equation :

$$L = \left[\frac{V_{OUT}}{f \times \Delta I_{L(MAX)}} \right] \times \left[1 - \frac{V_{OUT}}{V_{IN(MAX)}} \right]$$

The inductor's current rating (defined by a temperature rise from 25°C ambient to 40°C) should be greater than the maximum load current and its saturation current should be greater than the short-circuit peak current limit.

Input and Output Capacitor Selection

An input capacitor, C_{IN} , is needed to filter out the trapezoidal current at the source of the high-side MOSFET. To prevent large ripple current, a low ESR input capacitor sized for the maximum RMS current should be used. The RMS current is given by :

$$I_{RMS} = I_{OUT(MAX)} \frac{V_{OUT}}{V_{IN}} \sqrt{\frac{V_{IN}}{V_{OUT}} - 1}$$

This formula has a maximum at $V_{IN} = 2V_{OUT}$, where $I_{RMS} = I_{OUT(MAX)} / 2$. This simple worst-case condition is commonly used for design. Choose a capacitor rated at a higher temperature than required. Several capacitors may also be paralleled to meet the size or height requirements of the design. Ceramic capacitors have high ripple current, high voltage rating and low ESR, which makes them ideal for switching regulator applications. However, they can also have a high voltage coefficient and audible piezoelectric effects. The high Q of ceramic capacitors with trace inductance can lead to significant ringing. When a ceramic capacitor is used at the input and the power is supplied by a wall adapter through long wires, a load step at the output can induce ringing at the input, V_{IN} . At best, this ringing can couple to the output and be mistaken as loop instability. At worst, a sudden inrush of current through the long wires can potentially cause a voltage spike at V_{IN} large enough to damage the part. Thus, care must be taken to select a suitable input capacitor.

The selection of C_{OUT} is determined by the required ESR to minimize output voltage ripple. Moreover, the amount of bulk capacitance is also a key for C_{OUT} selection to ensure that the control loop is stable. Loop stability can be checked by viewing the load transient response. The output voltage ripple, ΔV_{OUT} , is determined by :

$$\Delta V_{OUT} \leq \Delta I_L \left[ESR + \frac{1}{8f_{OSC} C_{OUT}} \right]$$

where f_{OSC} is the switching frequency and ΔI_L is the inductor ripple current. The output voltage ripple will be the highest at the maximum input voltage since ΔI_L increases with input voltage. Multiple capacitors placed in parallel may be needed to meet the ESR and RMS current handling requirement. Ceramic capacitors have excellent low ESR characteristics, but can have a high voltage coefficient and audible piezoelectric effects. The high Q of ceramic capacitors with trace inductance can also lead to significant ringing. Nevertheless, high value, low cost ceramic capacitors are now becoming available in smaller case sizes. Their high ripple current, high voltage rating and low ESR make them ideal for switching regulator applications.

I²C Interface Function

RT5735A can be used by I²C interface to select V_{OUT} voltage level, over current limit level, thermal warning temperature level, PWM control mode, and so on. The register of each function can be found from the following register map and it also explains how to use these function.

V_{OUT} Selection : RT5735A has external VSEL pin to select PROGSEL1(0X10) or PROGSEL0(0X11) which can control V_{OUT} from 0.6V to 1393.75mV with 7bits resolution. Pull VSEL to high is for PROGSEL1 and pull VSEL to low is for PROGSEL0. If VSELGT bit in the COMMAND register is set to 0, V_{OUT} will only be controlled by PROGSEL1.

Discharge Function : In the PGOOD register DISCHG bit is set to 1 can let V_{OUT} discharge by internal resistor when converter shuts down. If setting to 0 V_{OUT} will decrease depending on the loading.

Power Good Function : In the PGOOD register PGDCDC bit can control if external PG pin is active. After PG function is active if PGDVS pin is 0, PG will not change state during V_{OUT} changing. Once PGDVS pin is 1 PG will be low when V_{OUT} is much lower than V_{REF} during V_{OUT} changing.

Slew Rate Setting : RT5735A can control slew rate as V_{OUT} changing between two voltage levels for both up and down. In the time register DVS_UP bits can control up-speed when in the LIMCONF register DVS_DOWN can control down-speed. DVS_DOWN is valid only when converter is at PWM mode or DVSMODE bit is 1.

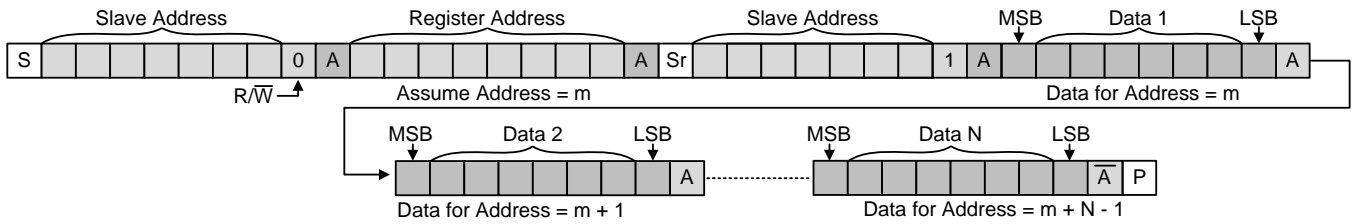
Force PWM Mode : In the COMMAND register PWMSEL0 and PWMSEL1 can decide converter is always at PWM mode or enters power saving mode at light load condition. During output voltage is changed from high to low at light load, setting DVSMODE bit to 1 will make transition operate at PWM mode and output voltage will decrease quickly. If setting to 0, the output voltage will decrease depending on the loading.

Over Current Level : RT5735A has four levels of over current limit to be selected. Using IOC bits in the LIMCONF register can change different inductor valley current limit level.

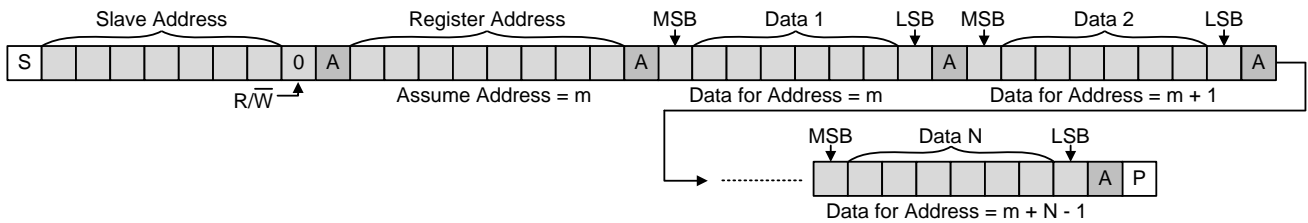
Thermal Shutdown Protection : The default REARM bit in the LIMCONF register is 1. RT5735A will shut down switching operation when the junction temperature exceeds 150 °C. Once the junction temperature cools down by approximately 30°C the IC will resume normal operation with a complete soft-start. When REARM bit is set to 0, once the device triggers the OTP, the system will be latched and the output voltage will no longer be regulated during OTP latched state. Re-start input voltage or EN pin can unlatch the protection state. Using I²C to shutdown the system and then re-enable it will also unlatch UVP function.

The RT5735A default I²C slave address = 7'b0011100. I²C interface support fast mode (bit rate up to 400kb/s). The write or read bit stream (N≥1) is shown below :

Read N bytes from RT5735A



Write N bytes to RT5735A



Legend: Driven by Master, Driven by Slave (RT5735A), P Stop, S Start, Sr Repeat Start

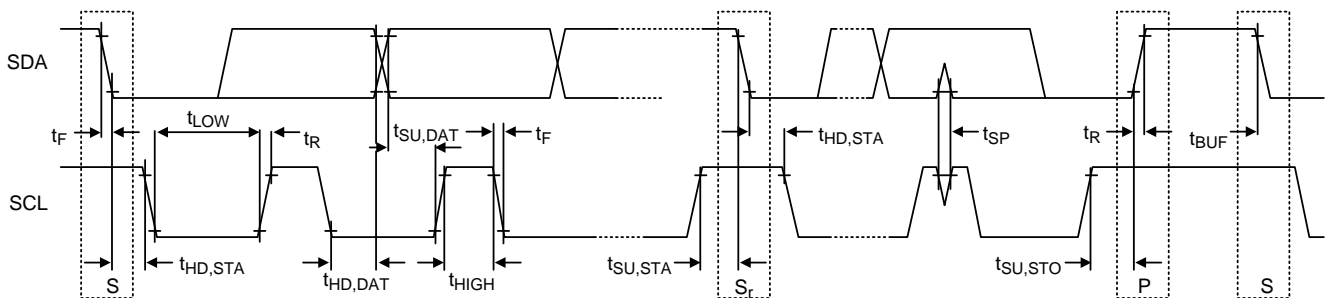


Figure 1. I²C Read and Write Stream and Timing Diagram

RT5735A can also support High-speed mode (bit rate up to 3.4Mb/s) with access code 08H. Figure 2 and Figure 3 show detail transfer format. Hs-mode can only commence after the following conditions (all of which are in F/S-mode) :

- ▶ START condition (S)
- ▶ 8-bit master code (00001xxx)
- ▶ not-acknowledge bit (\bar{A})

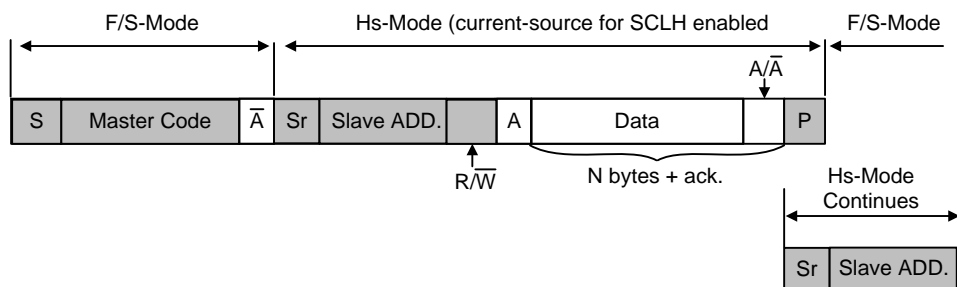


Figure 2. Data Transfer Format in Hs-mode

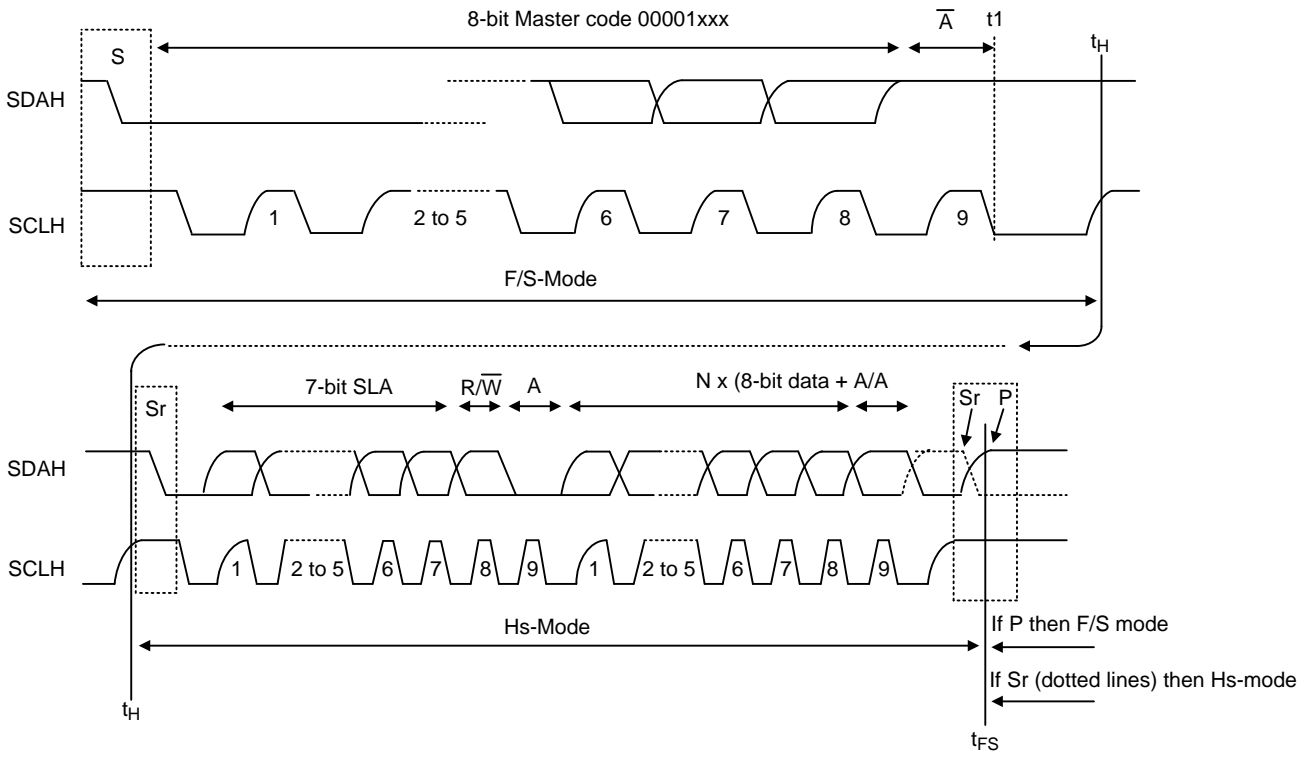


Figure 3. A Complete Hs-mode Transfer

| Address Name | Register Address | Bit7 | Bit6 | Bit5 | Bit4 | Bit3 | Bit2 | Bit1 | Bit0 | |
|--------------|------------------|------------|-------------|-----------------|------------|-------------|------|---------------|-------|--------|
| PRODUCT_ID | 0x03 | Meaning | PRODUCT_ID | | | | | | | |
| | | Default | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| REVISION_ID | 0x04 | Meaning | REVISION_ID | | | | | | | |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| FEATURE_ID | 0x05 | Meaning | FEATURE_ID | | | | | | | |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| VENDER ID | 0x06 | Meaning | VENDER_ID | | | | | | | |
| | | Default | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| PROGVSEL1 | 0x10 | Meaning | ENVSEL1 | Vout_VSEL1[6:0] | | | | | | |
| | | Default | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 |
| | | Read/Write | RW | RW | RW | RW | RW | RW | RW | RW |
| PROGVSEL0 | 0x11 | Meaning | ENVSEL0 | Vout_VSEL0[6:0] | | | | | | |
| | | Default | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |
| | | Read/Write | R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| PGOOD | 0x12 | Meaning | RESV | | | DISCHG | RESV | | PGDVS | PGDCDC |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R/W | R | R | R/W | R/W |
| TIME | 0x13 | Meaning | RESV | | | DVS_UP[2:0] | | RESV | | |
| | | Default | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 |
| | | Read/Write | R | R | R | R/W | R/W | R/W | R | R |
| COMMAND | 0x14 | Meaning | PWMSEL0 | PWMSEL1 | DVSMODE | RESV | | | | VSELGT |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| | | Read/Write | R/W | R/W | R/W | R | R | R | R | R/W |
| LIMCONF | 0x16 | Meaning | IOC<1:0> | | TPWTH<1:0> | | RESV | DVS_DOWN<1:0> | | REARM |
| | | Default | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 |
| | | Read/Write | R/W | R/W | R/W | R/W | R | R/W | R/W | R/W |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|------------------|------------|------------|------|------|------|------|------|------------|---|
| PRODUCT_ID | 0x03 | Meaning | PRODUCT_ID | | | | | | | |
| | | Default | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| PRODUCT_ID | | PRODUCT_ID | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|------------------|-------------|-------------|------|------|------|------|------|------------|---|
| REVISION_ID | 0x04 | Meaning | REVISION_ID | | | | | | | |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| REVISION_ID | | REVISION_ID | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|------------------|------------|------------|------|------|------|------|------|------------|---|
| FEATURE_ID | 0x05 | Meaning | FEATURE_ID | | | | | | | |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| FEATURE_ID | | FEATURE_ID | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|------------------|------------|------|------|------|------|------|------|------------|---|
| VENDER ID | 0x06 | Meaning | RESV | | | | | | | |
| | | Default | 1 | 0 | 0 | 0 | 1 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R | R | R | R | R |
| VENDER ID | | VENDER ID | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|-----------------|------------------|--|---------|-----------------|------|------|------|------|------------|----|
| PROGVSEL1 | 0x10 | Meaning | ENVSEL1 | Vout_VSEL1[6:0] | | | | | | |
| | | Default | 0 | 1 | 0 | 1 | 0 | 0 | 0 | 0 |
| | | Read/Write | RW | RW | RW | RW | RW | RW | RW | RW |
| ENVSEL1 | | EN Pin Gating for VSEL internal signal = High 0 : Disabled 1 : Enabled | | | | | | | | |
| Vout_VSEL1[6:0] | | VID Table satisfy : SEL[6:0] = 1111111 : VOUT = 1393.75mV ... SEL[6:0] = 1010000: VOUT = 1.1V (default) ... SEL[6:0] = 0000000 :0.6V 6.25mV step for DCDC, VOUT = 600mV + 6.25mV x SEL | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|-----------------|------------------|--|-------------------------|------|------|------|------|------|------------|-----|
| PROGVSEL0 | 0x11 | Meaning | ENVSEL0 Vout_VSEL0[6:0] | | | | | | | |
| | | Default | 0 | 0 | 0 | 1 | 0 | 0 | 0 | 0 |
| | | Read/Write | R/W | R/W | R/W | R/W | R/W | R/W | R/W | R/W |
| ENVSEL0 | | EN Pin Gating for VSEL internal signal= Low 0 : Disabled 1 : Enabled | | | | | | | | |
| Vout_VSEL0[6:0] | | VID Table satisfy : SEL[6:0] = 1111111 : VOUT = 1393.75mV ... SEL[6:0] = 0010000 : VOUT = 0.7V (default) ... SEL[6:0] = 0000000 : 0.6V 6.25mV step for DCDC, VOUT = 600mV + 6.25mV x SEL | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|------------------|--|------|------|------|--------|------|------|------------|--------|
| PGOOD | 0x12 | Meaning | RESV | | | DISCHG | RESV | | PGDVS | PGDCDC |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| | | Read/Write | R | R | R | R/W | R | R | R/W | R/W |
| RESV | | Reserved bits | | | | | | | | |
| DISCHG | | Active discharge bit enabling 0 : Discharge path disabled 1 : Discharge path enabled | | | | | | | | |
| RESV | | Reserved bits | | | | | | | | |
| PGDVS | | Power good active on DVS 0 : Disabled 1 : Enabled | | | | | | | | |
| PGDCDC | | Power good enabling 0 : Disabled 1 : Enabled | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|------------------|--|----------|------|------|-------------|------|----------|------------|---|
| TIME | 0x13 | Meaning | Reserved | | | DVS_UP[2:0] | | Reserved | | |
| | | Default | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 1 |
| | | Read/Write | R | R | R | R/W | R/W | R/W | R | R |
| RESV | | Reserved bits | | | | | | | | |
| DVS_UP[2:0] | | DVS slew rate for up 000 : 64mV/μS 001 : 16mV/μS 010 : 32mV/μS 011 : 8mV/μS 100 : 4mV/μS 101 : 4mV/μS 110 : 32mV/μS 111 : 8mV/μS | | | | | | | | |
| RESV | | Reserved bits | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) |
|---------------|--|------------|---------|---------|---------|------|------|------|------------|
| COMMAND | 0x14 | Meaning | PWMSEL0 | PWMSEL1 | DVSMODE | RESV | | | VSELGT |
| | | Default | 0 | 0 | 0 | 0 | 0 | 0 | 1 |
| | | Read/Write | R/W | R/W | R/W | R | R | R | R |
| PWMSEL0 | Operation mode for VSEL internal signal = Low 0 : Auto 1 : Forced PWM | | | | | | | | |
| PWMSEL1 | Operation mode for VSEL internal signal = High 0 : Auto 1 : Forced PWM | | | | | | | | |
| DVSMODE | DVS transition mode selection 0 : Auto 1 : Forced PWM | | | | | | | | |
| RESV | Reserved bits | | | | | | | | |
| VSELGT | VSEL Pin gating 0 : Disabled 1 : Enabled | | | | | | | | |

| Register Name | Register Address | b[7] (MSB) | b[6] | b[5] | b[4] | b[3] | b[2] | b[1] | b[0] (LSB) | |
|---------------|--|------------|----------|------|------------|------|------|---------------|------------|-------|
| LIMCONF | 0x16 | Meaning | IOC<1:0> | | TPWTH<1:0> | | RESV | DVS_DOWN<1:0> | | REARM |
| | | Default | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 |
| | | Read/Write | R/W | R/W | R/W | R/W | R | R/W | R/W | R/W |
| IOC[1:0] | Inductor valley current settings 00 = 4A (typ.) 01 = 4.7A (typ.) 10 = 5.4A (typ.) 11 = 6.4A (typ.) | | | | | | | | | |
| TPWTH[1:0] | Thermal pre-warning threshold settings 00 = 83°C 01 = 94°C 10 = 105°C 11 = 116°C | | | | | | | | | |
| RESV | Reserved bits | | | | | | | | | |
| DVS_DOWN[1:0] | DVS slew rate for down 00 = 32mV/μs 01 = 4mV/μs 10 = 8mV/μs 11 = 16mV/μs | | | | | | | | | |
| REARM | Recovery of device after TSD 0 : No Recovery after TSD 1 : Recovery after TSD | | | | | | | | | |

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For WL-CSP-20B 1.6x2 (BSC) package, the thermal resistance, θ_{JA} , is 55°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at $T_A = 25^\circ\text{C}$ can be calculated by the following formula :

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (55^\circ\text{C/W}) = 1.8\text{W for WL-CSP-20B 1.6x2 (BSC) package}$$

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . The derating curve in Figure 4 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

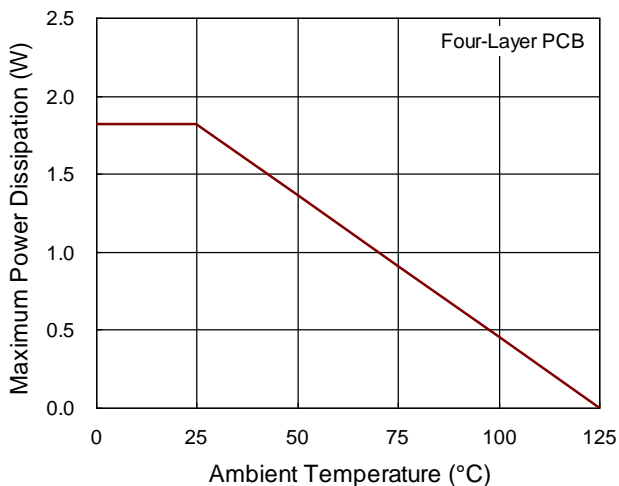


Figure 4. Derating Curve of Maximum Power Dissipation

Layout Considerations

For best performance of the RT5735A, the following layout guidelines must be strictly followed.

- ▶ Input capacitor must be placed as close to the IC as possible.
- ▶ SW should be connected to inductor by wide and short trace. Keep sensitive components away from this trace.
- ▶ Keep every trace connected to pin as wide as possible for improving thermal dissipation.

Top layer
2nd layer

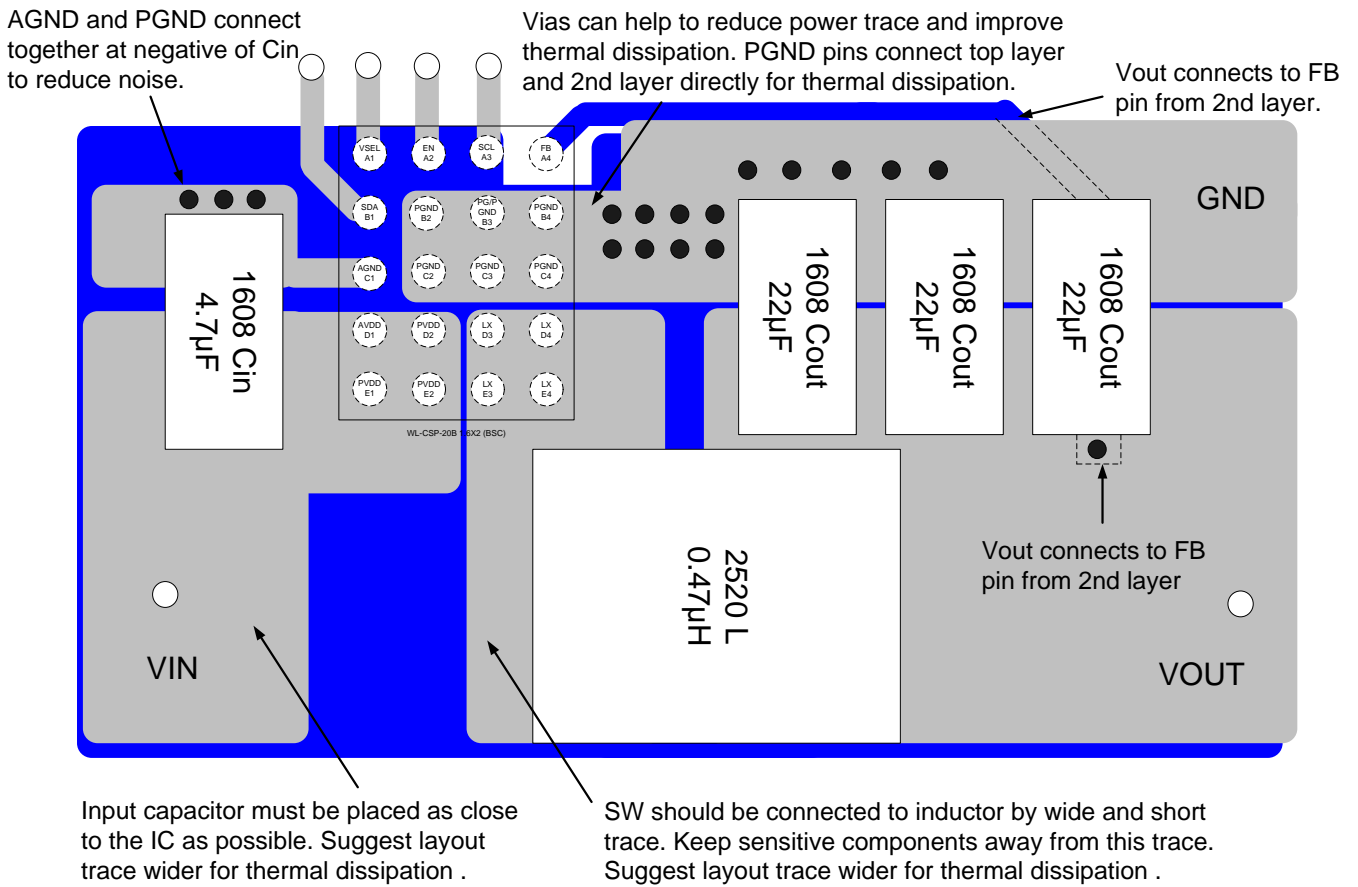
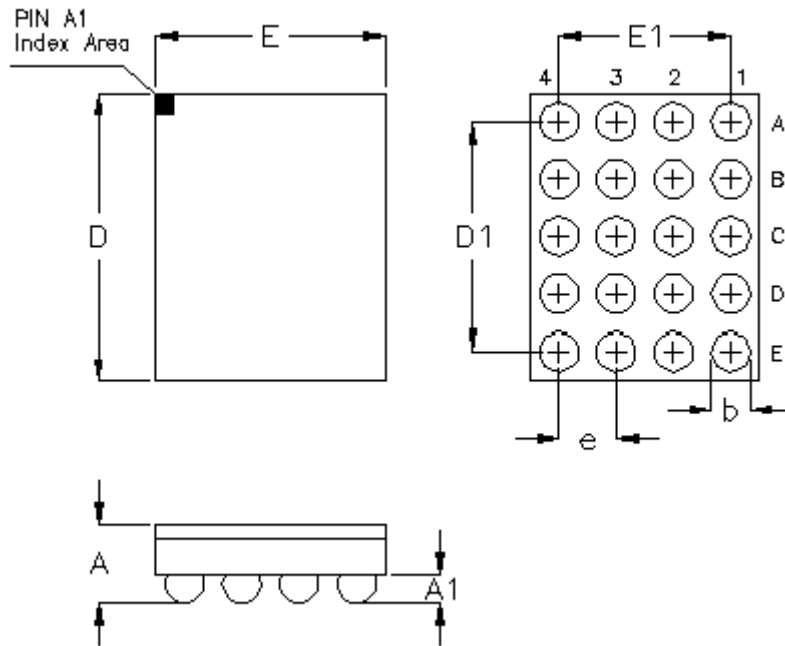


Figure 5. PCB Layout Guide

Outline Dimension



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.500 | 0.600 | 0.020 | 0.024 |
| A1 | 0.170 | 0.230 | 0.007 | 0.009 |
| b | 0.240 | 0.300 | 0.009 | 0.012 |
| D | 1.950 | 2.050 | 0.077 | 0.081 |
| D1 | 1.600 | | 0.063 | |
| E | 1.550 | 1.650 | 0.061 | 0.065 |
| E1 | 1.200 | | 0.047 | |
| e | 0.400 | | 0.016 | |

20B WL-CSP 1.6x2 Package (BSC)

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